MOSFET – Power, Single, N-Channel 60 V, 21 mΩ, 25 A

Features

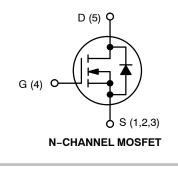
- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

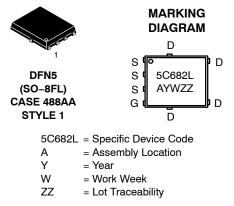


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
60 V	21 mΩ @ 10 V	25 A
00 V	$31.5~\mathrm{m}\Omega$ @ $4.5~\mathrm{V}$	23 A





MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	60	V
Gate-to-Source Voltage	е		V _{GS}	±20	V
Continuous Drain		$T_{C} = 25^{\circ}C$	۱ _D	25	А
Current R _{θJC} (Notes 1, 3)	Steady	T _C = 100°C		18	
Power Dissipation	State	$T_{C} = 25^{\circ}C$	PD	28	W
R _{θJC} (Note 1)		$T_{C} = 100^{\circ}C$		14	
Continuous Drain		$T_A = 25^{\circ}C$	I _D	8.8	А
Current R _{θJA} (Notes 1, 2, 3)	Steady	$T_A = 100^{\circ}C$		6.2	
Power Dissipation	State	T _A = 25°C	PD	3.5	W
R _{θJA} (Notes 1 & 2)		T _A = 100°C		1.7	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	130	А
Operating Junction and Storage Temperature			T _J , T _{stg}	–55 to + 175	°C
Source Current (Body Diode)			I _S	31	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 1.1 A)			E _{AS}	43	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	5.3	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	43	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

ORDERING INFORMATION

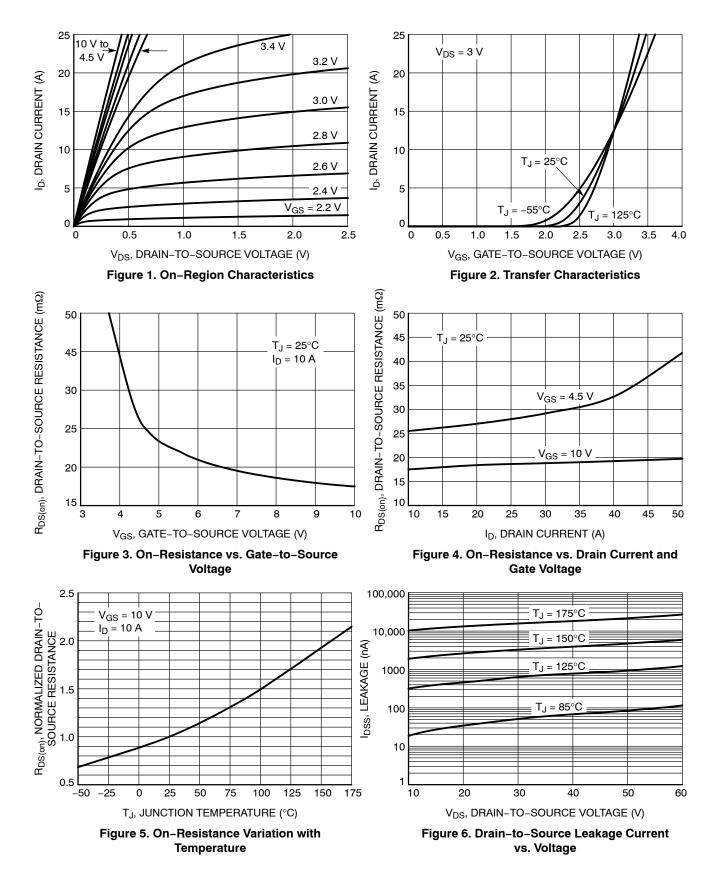
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise specified)

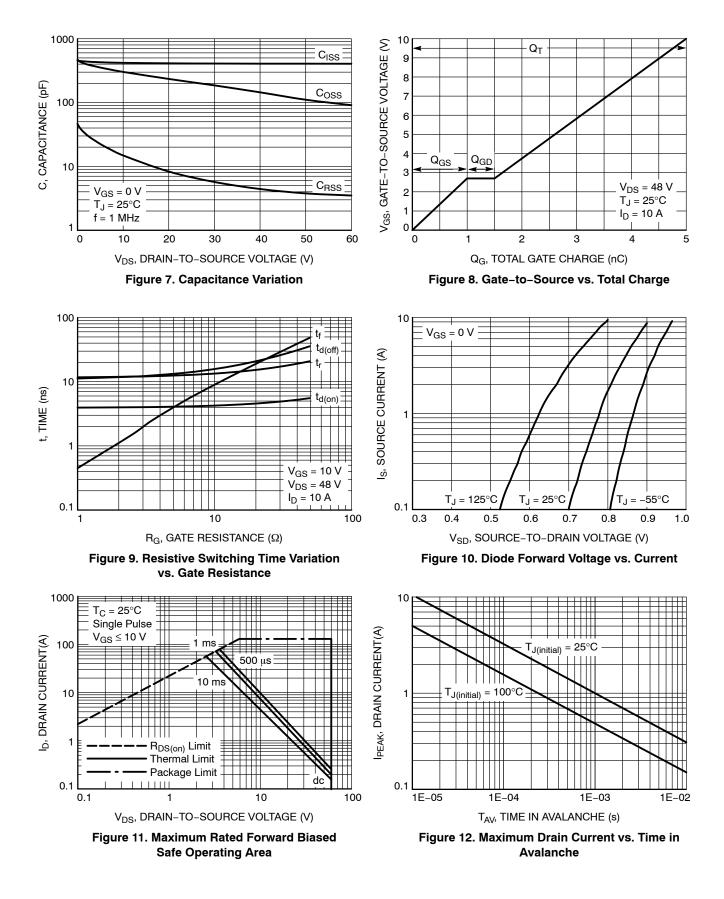
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS					•			
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 250 μA		60			V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				28		mV/°C	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 60 V	T _J = 25 °C T _J = 125°C			10 250	μΑ	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS}	, ,			100	nA	
ON CHARACTERISTICS (Note 4)	400		,				l	
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} = V _{DS} , I _D = 16 μA		1.2		2.0	V	
Threshold Temperature Coefficient	V _{GS(TH)} /T _J		1		-4.5		mV/°C	
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 10 A		18	21		
	()	V _{GS} = 4.5 V	I _D = 10 A		26	31.5	mΩ	
Forward Transconductance	9 _{FS}	V _{DS} =15 V, I _D	= 10 A		17		S	
CHARGES AND CAPACITANCES								
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 25 V			410			
Output Capacitance	C _{OSS}				210		pF	
Reverse Transfer Capacitance	C _{RSS}				7.0			
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 48 V; I_{D} = 10 A			2.5		nC	
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 48 V; I_{D} = 10 A			5.0		nC	
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 10 V, V _{DS} = 48 V; I _D = 10 A			0.6			
Gate-to-Source Charge	Q _{GS}				1.0		nC	
Gate-to-Drain Charge	Q _{GD}				0.5			
Plateau Voltage	V _{GP}				2.7		V	
SWITCHING CHARACTERISTICS (Note 5	5)					-	-	
Turn-On Delay Time	t _{d(ON)}				4.0			
Rise Time	tr	V _{GS} = 10 V, V _D	_s = 48 V,		12		ns	
Turn-Off Delay Time	t _{d(OFF)}	$I_D = 10 \text{ A}, \text{ R}_G$	= 2.5 Ω		12			
Fall Time	t _f	1			1.5		1	
DRAIN-SOURCE DIODE CHARACTERIS	TICS					-		
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$ $T_{J} = 25^{\circ}C$ 0.9		0.9	1.2			
			T _J = 125°C		0.8		V	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 10 A			18			
Charge Time	t _a				9.0		ns	
Discharge Time	t _b				9.0			
Reverse Recovery Charge	Q _{RR}				7.0		nC	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



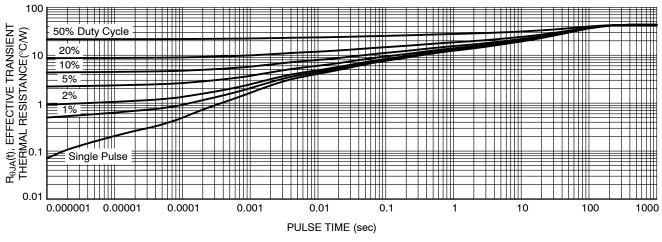


Figure	13.	Thermal	Characteristics
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DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS5C682NLT1G	5C682L	DFN5 (Pb–Free)	1500 / Tape & Reel
NTMFS5C682NLT3G	5C682L	DFN5 (Pb–Free)	5000 / Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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